

Description

The ICS728 combines the functions of a VCXO (Voltage Controlled Crystal Oscillator) and PLL (Phase Locked Loop) frequency doubler onto a single chip. Used in conjunction with an external pullable quartz crystal, this monolithic integrated circuit replaces more costly hybrid (canned) VCXO devices. The ICS728 is designed primarily for data and clock recovery applications within end products such as set-top box receivers.

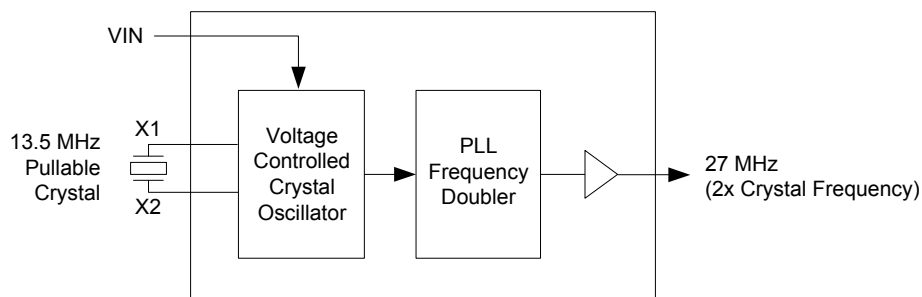
The ICS728 exhibits a moderate VCXO gain of 110 ppm/V typical, when used with a high quality external pullable quartz crystal.

The frequency of the on-chip VCXO is adjusted by an external control voltage input into pin VIN. Because VIN is a high impedance input, it can be driven directly from an PWM RC integrator circuit. Frequency output increases with VIN voltage input. The usable range of VIN is 0 to 3.3 V.

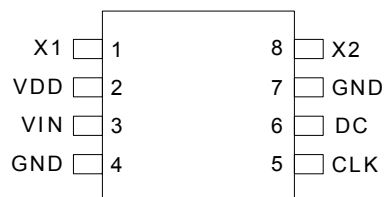
Features

- Ideal for set-top box applications using 13.5 MHz external pullable crystal to generate lock 27 MHz clock transport video clock
- On-chip VCXO with guaranteed pull range of ± 110 ppm minimum
- VCXO input tuning voltage 0 to 3.3 V
- Packaged in 8-pin SOIC (150 mil wide)
- Pb (lead) free package, ROHS compliant

Block Diagram



Pin Assignment



8-pin (150 mil) SOIC

Pin Descriptions

Pin Number	Pin Name	Pin Type	Pin Description
1	X1	Input	Crystal connection. Connect to the external pullable crystal.
2	VDD	Power	Connect to +3.3 V (0.01uf decoupling capacitor recommended).
3	VIN	Input	Voltage input to VCXO. Zero to 3.3 V analog input which controls the oscillation frequency of the VCXO.
4	GND	Power	Connect to ground.
5	CLK	Output	Clock output.
6	DC	—	Do not connect to this pin
7	GND	Power	Connect to ground.
8	X2	Input	Crystal connection. Connect to the external pullable crystal.

External Component Selection

The ICS728 requires a minimum number of external components for proper operation.

Decoupling Capacitor

A decoupling capacitor of 0.01 μ F must be connected between VDD (pin 2) and GND (pin 4), as close to these pins as possible. For optimum device performance, the decoupling capacitor should be mounted on the component side of the PCB. Avoid the use of vias in the decoupling circuit.

Series Termination Resistor

When the PCB trace between the clock output (CLK, pin 5) and the load is over 1 inch, series termination should be used. To series terminate a 50 Ω trace (a commonly used trace impedance) place a 33 Ω resistor in series with the clock line, as close to the clock output pin as possible. The nominal impedance of the clock output is 20 Ω .

Quartz Crystal

The ICS728 VCXO function consists of the external crystal and the integrated VCXO oscillator circuit. To assure the best system performance (frequency pull range) and reliability, a crystal device with the recommended parameters (shown below) must be used, and the layout guidelines discussed in the following section shown must be followed.

The frequency of oscillation of a quartz crystal is determined by its "cut" and by the load capacitors connected to it. The ICS728 incorporates on-chip variable load capacitors that "pull" (change) the frequency of the crystal. The crystal specified for use with the ICS728 is designed to have zero frequency error when the total of on-chip + stray capacitance is 14 pF.

Recommended Crystal Parameters:

Initial Accuracy at 25° C	±20 ppm
Temperature Stability	±30 ppm
Aging	±20 ppm
Load Capacitance	14 pF
Shunt Capacitance, C0	7 pF Max
C0/C1 Ratio	250 Max
Equivalent Series Resistance	35 Ω Max

The third overtone mode of the crystal and all spurs must be >100 ppm distant from 3x the fundamental resonance

measured with a physical load of 14 pF.

The external crystal must be connected as close to the chip as possible and should be on the same side of the PCB as the ICS728. There should be no vias between the crystal pins and the X1 and X2 device pins. There should be no signal traces underneath or close to the crystal.

Crystal Tuning Load Capacitors

The crystal traces should include pads for small fixed capacitors, one between X1 and ground, and another between X2 and ground. Stuffing of these capacitors on the PCB is optional. The need for these capacitors is determined at system prototype evaluation, and is influenced by the particular crystal used and by PCB layout. The typical required capacitor value is 1 to 4 pF.

To determine the need for and value of the crystal adjustment capacitors, you will need a PC board of your final layout, a frequency counter capable of 1 ppm resolution and accuracy, two power supplies, and some samples of the crystals which you plan to use in production, along with measured initial accuracy for each crystal at the specified crystal load capacitance, CL.

To determine the value of the crystal capacitors:

1. Connect VDD of the ICS728 to 3.3 V. Connect pin 3 of the ICS728 to the second power supply. Adjust the voltage on pin 3 to 0V. Measure and record the frequency of the CLK output.
2. Adjust the voltage on pin 3 to 3.3 V. Measure and record the frequency of the same output.

To calculate the centering error:

$$\text{Error} = 10^6 \times \left[\frac{(f_{3.0V} - f_{\text{target}}) + (f_{0V} - f_{\text{target}})}{f_{\text{target}}} \right] - \text{error}_{\text{xtal}}$$

Where:

f_{target} = nominal crystal frequency

$\text{error}_{\text{xtal}}$ = actual initial accuracy (in ppm) of the crystal being measured

If the centering error is less than ±25 ppm, no adjustment is needed. If the centering error is more than 25 ppm negative, the PC board has excessive stray capacitance and a new PCB layout should be considered to reduce stray

capacitance. (Alternately, the crystal may be re-specified to a higher load capacitance. Contact IDT for details.) If the centering error is more than 25 ppm positive, add identical fixed centering capacitors from each crystal pin to ground. The value for each of these caps (in pF) is given by:

$$\text{External Capacitor} = 2 \times (\text{centering error}) / (\text{trim sensitivity})$$

Trim sensitivity is a parameter which can be supplied by your crystal vendor. If you do not know the value, assume it is 30 ppm/pF. After any changes, repeat the measurement to verify that the remaining error is acceptably low (typically less than ± 25 ppm).

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the ICS728. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	7 V
All Inputs and Outputs	-0.5 V to VDD+0.5 V
Storage Temperature	-65 to +150° C
Soldering Temperature	260° C

Recommended Operation Conditions

Parameter	Min.	Typ.	Max.	Units
Ambient Operating Temperature	0		+70	°C
Power Supply Voltage (measured in respect to GND)	+3.15		+3.45	V
Reference crystal parameters	Refer to page 3			

DC Electrical Characteristics

VDD=3.3 V \pm 5% , Ambient temperature 0 to +70° C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Operating Voltage	VDD		3.15		3.45	V
Output High Voltage	V _{OH}	I _{OH} = -12 mA	2.4			V
Output Low Voltage	V _{OL}	I _{OL} = 12 mA			0.4	V
Output High Voltage (CMOS Level)	V _{OH}	I _{OH} = -4 mA	VDD-0.4			V
Operating Supply Current	IDD	Output = 27 MHz, no load		12		mA
Short Circuit Current	I _{OS}			\pm 50		mA
VIN, VCXO Control Voltage	V _{IA}		0		3.3	V

AC Electrical Characteristics

VDD = 3.3 V \pm 5%, Ambient Temperature 0 to +70° C, unless stated otherwise

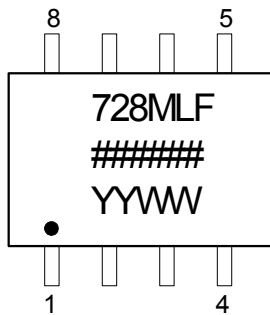
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Output Frequency	F _O			27		MHz
Crystal Pullability	F _P	0V \leq VIN \leq 3.3 V, Note 1	\pm 110			ppm
VCXO Gain		VIN = VDD/2 \pm 1 V, Note 1		120		ppm/V
Output Rise Time	t _{OR}	0.8 to 2.0 V, C _L =15 pF			1.5	ns
Output Fall Time	t _{OF}	2.0 to 0.8 V, C _L =15 pF			1.5	ns
Output Clock Duty Cycle	t _D	Measured at 1.4 V, C _L =15 pF	40	50	60	%
Maximum Output Jitter, short term	t _J	C _L =15 pF		100		ps

Note 1: External crystal device must conform with Pullable Crystal Specifications listed on page 3.

Thermal Characteristics

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Thermal Resistance Junction to Ambient	θ_{JA}	Still air		150		°C/W
	θ_{JA}	1 m/s air flow		140		°C/W
	θ_{JA}	3 m/s air flow		120		°C/W
Thermal Resistance Junction to Case	θ_{JC}			40		°C/W

Marking Diagram

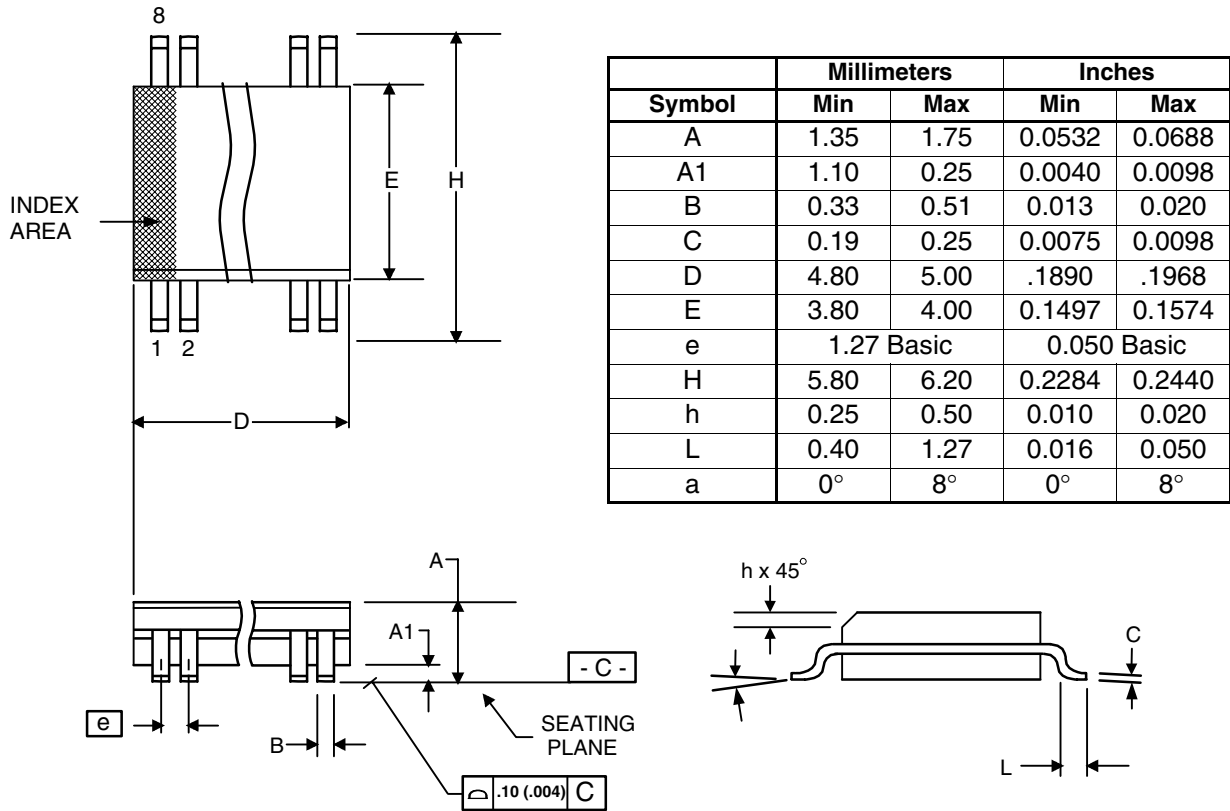


Notes:

1. ##### is the lot number.
2. YYWW is the last two digits of the year and week that the part was assembled.
3. "LF" denotes Pb (lead) free package.
4. Bottom marking: (origin)
Origin = country of origin of not USA.

Package Outline and Package Dimensions (8-pin SOIC, 150 Mil. Narrow Body)

Package dimensions are kept current with JEDEC Publication No. 95



Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
728MLF	see page 6	Tubes	8-pin SOIC	0 to +70° C
728MLFT		Tape and Reel	8-pin SOIC	0 to +70° C

“LF” suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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Revision History

Rev.	Originator	Date	Description of Change
A	J. Sarma	12/14/04	Release from Prelim to Final; release as General purpose device.
B	J. Sarma	01/25/05	Add marking diagrams; add LF.
C		11/04/09	Added EOL note for non-green parts.
D		05/13/10	Removed EOL note and non-green parts.

ICS728

LOW COST 27 MHZ 3.3 VOLT VCXO

VCXO

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